EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	80	"5654237" "5470791" "5304510" "5192714"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/28 08:39
L2	19	carbon and 1	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/28 08:40
L3	2281	(257/288).OCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:11
L4	278	(257/388).OCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:11
L5	341	(257/407).OCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:11
L6	1246	(257/412).OOLS.	US-PGPUB; USPAT; USOOR	OR	OFF	2010/05/28 09:11
L7	563	(257/413).OOLS.	US-PGPUB; USPAT; USOOR	OR	OFF	2010/05/28 09:11
L8	634	(257/e29.16).OOLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:13
L9	305	(257/e29.161).COLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:13
L10	506	(257/e21.621).OOLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:13
L11	274	(257/e21.622).OOLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:14
L12	335	(257/e21.623).OOLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:14
L13	526	(257/e21.635).OOLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:14
L14	720	(257/e21.636).OCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:14
L15	1563	(257/e21.637).OOLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/05/28 09:14

S2	25	"6130145"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/26 19:32
S3	47	[*5913145*	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/26 19:50
S4	45047	(substrate or wafer) and (oxide or (gate insulat\$3)) and ((Tungsten nitride) or (tungsten carbide) or (tungsten silicide) or WN or WC)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 12:00
S5	1240	(((Tungsten nitride) or (tungsten carbide) or (tungsten silicide) or WS or WN or WC) with (onto or on or over or above) with (oxide or (gate insulat\$3))) and S4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 12:02
S 6	252	(((poly or (poly S)) or (poly silicon) or (polyorystalline Si) with (onto or on or above or over) with (((Tungsten ittride) or (tungsten silicide) or (tungsten silicide) or WN or WN) or WC) and SS	US-PGPUB; USPAT; USOCR; FPRS; EFO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 12:03
S8	8	(((poly or (poly S) or (poly silicon) or (polyorystalline Silicon) or (polyorystalline S)) adj3 (onto or on or above or over) adj3 (((Tungsten ittride) or (tungsten silicide) or (tungsten silicide) or WS or WN or WC)) and SS	US-PGPUB; USPAT; USOCR; FPRS; EFO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 12:33
S9	0	(((poly or (poly S)) or (poly silicon) or (polycrystalline silicon) or (polycrystalline S)) adj2 (onto or on or above or over) adj2 ((Tungsten nitride) or (tungsten 1carbide) or (tungsten silicide) or WS or WN or WO)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 12:39

S10	9	((poly or (poly S) or (poly silicon) or (polycrystalline silicon) or (polycrystalline S)) adj3 (onto or on or above or over) adj3 ((Tungsten nitride) or (tungsten silicide) or (tungsten silicide) or WS or WN or WC)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	**************************************	2010/05/27 12:39
S11	47021	((tungsten carbid) or WC)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 12:48
S12	6090	(substrate or wafer) and (oxide or (gate insulat\$3)) and S11	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 12:49
S13	3	"W(CO)" and S12	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 12:49
S15	7	(((tungsten carbid) or WC) with (onto or over or above or on) with (poly or (poly Si) or (poly silicon) or (polycrystalline silicon) or (polycrystalline Si))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 12:53
S16	287943	(precursor or carrier) with (carbon or C)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 17:38
S17	16416	((precursor or carrier) with (Slicon or Sl)) and ((precursor or carrier) with (carbon or Cl)) and ((precursor or carrier) with (nitrogen or Nl)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 17:41
S18	1113	(substrate or wafer) and ((gate oxide) or (gate insulat\$3)) and S17	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2010/05/27 17:41

S19	835219	(precursor or carrier or source) with (metal or Tungsten or titanium or tantallum or cobalt or Co or W or Ti or Ta or Mo or Re or Ru or Ni or nickle or ruthenium or molybdenum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 17:45
S20	916	S18 and S19	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 17:45
S21	130	(ethylene or allyl alcohol or (formic acide) or (tetrahydrofuran)) and \$20	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 17:48
S22	76945	(precursor or carrier) with (carbon)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 17:57
\$23	1308	(substrate or wafer) and ((gate oxide) or (gate insulat\$3)) and \$22	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 17:57
S 24	997	S19 and S23	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 17:58
S25	194	(ethylene or (allyl alcohol) or (formic acide) or (tetrahydrofuran)) and \$24	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 17:58
S26	20	("6218711" "6352872" "6395589" "6406951" "6492694" "6537369" "6603156" "6624483" "6727550").PN. OR ("6909186").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2010/05/27 18:53
S27	35	((WN) or (tungsten nitride)) same (dop\$3 or impaint\$5) same carbon same gate	US-PGPUB; USPAT; USOCR	ADJ	ON	2010/05/27 19:25

S28	8	((WCN) or (tungsten carbon nitride)) same barrier same gate	US-PGPUB; USPAT; USOOR	ADJ	ON	2010/05/27 19:48
S29	196	((WCN) or (tungsten carbon nitride)) same barrier	US-PGPUB; USPAT; USOOR	ADJ	ON	2010/05/27 19:55
S30	5	((tungsten silicide) or WS) and (poly or (poly Si) or (poly silicon) or (polycrystalline silicon) or (polycrystalline Si)) and S29	US-PGPUB; USPAT; USOCR	ADJ	ON	2010/05/27 19:56
S31	7	((metal Siticide) or ((titanium or tantalum or ruthenium or nickle or molybdenum or Cobalt or W or Ta or Ti or Co or Ni or Re or Ru or Mo) silicide)) and (poly or (poly Si) or (poly silicon) or (polycrystalline silicon) or (polycrystalline Si)) and S29	US-PGPUB; USPAT; USOOR	ADJ	ON	2010/05/27 20:02
S32	115	(metal carbon nitride) or ((titanium or tantalum or ruthenium or nickle or molybdenum or Cobalt or W or Ta or Ti or Co or Ni or Re or Ru or Mo) ((carbon nitride) or (CN))) same barrier and gate	US-PGPUB; USPAT; USOCR	ADJ	ON	2010/05/27 20:04
S35	2	JP "2003273350"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 21:01
S 36	3	"20050110098"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 21:02
\$37	127	(work function) with control \$4 with (CONTENT OR AMOUNT OR RATIO OR CONCENTRATION) WITH (N or S or nitrogen or silicon)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 21:12

S38	133	"6027961"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 21:28
S41	2	jp "10303412"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/27 21:50
S43	267	(ammonia or "NH.sub.3") and (W(CO)".sub.6") and gate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/28 06:31
S44	2	"20010014521"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/28 07:17

EAST Search History (Interference)

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